

NX6350EP Series

Data Sheet

LASER DIODE

1 270/1 290/1 310/1 330 nm AlGaInAs MQW-DFB LASER DIODE

FOR 40GBASE-LR4 APPLICATION

R08DS0066EJ0100

Rev.1.00

Aug 14, 2012

DESCRIPTION

The NX6350EP series is a 1 270/1 290/1 310/1 330 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD.

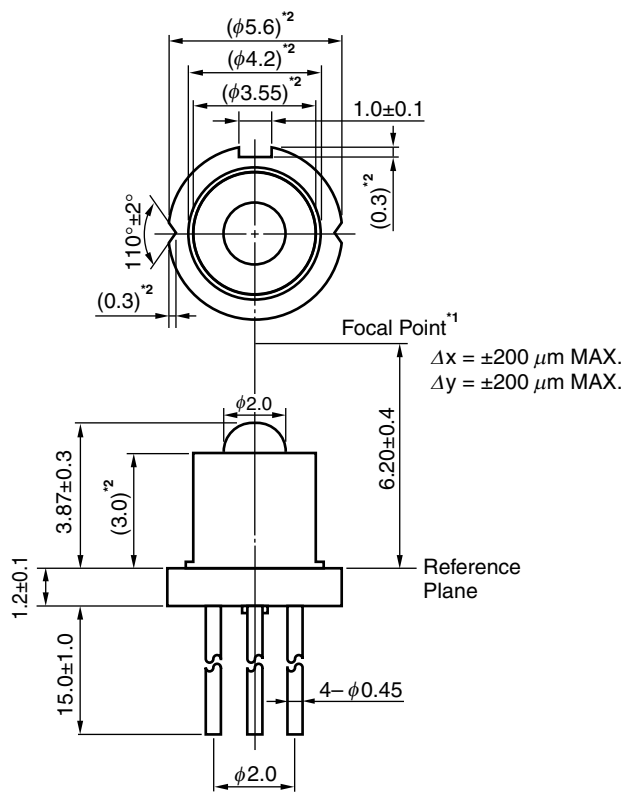
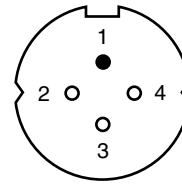
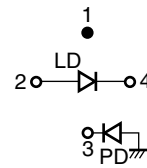
APPLICATIONS

- 40GBASE-LR4
- Bi-Directional 10G SFP+ (CPRI,10G-Ethernet)

FEATURES

- | | |
|------------------------------------|--|
| • Optical output power | $P_O = 8.5 \text{ mW}$ |
| • Low threshold current | $I_{th} = 8 \text{ mA}$ |
| • Differential efficiency | $\eta_d = 0.35 \text{ W/A}$ |
| • Wide operating temperature range | $T_C = -5 \text{ to } +85^\circ\text{C}$ |
| • InGaAs monitor PIN-PD | |
| • CAN package | $\phi 5.6 \text{ mm}$ |
| • Focal point | 6.2 mm |



PACKAGE DIMENSIONS (UNIT: mm)**BOTTOM VIEW****PIN CONNECTIONS**

*1 Focal Point: A point to get maximum optical output power from fiber.

*2 () indicates nominal dimension.